	Туре	Hits	Search Text	DBs
1	IS&R	-	("5610742").PN.	USPAT
2	BRS	17	243719"   "4292370"   "4315668"   "4339482"   "437850"   "4640584"   "4695490"   "4709991"   "486442"   "5106411"   "5150239"   "5188692"   "518080"   "5313322").PN.	USPAT
3	BRS	13	("4135789"   "4222635"   "4227779"   "4297401"   "4325610"   "4388139"   "4401537"   "4418102"   "4470668"   "4494825"   "4500171"   "4514041"   "4536060").PN.	USPAT
4	IS&R	0	432	USPAT
5	IS&R	9	(("4470668") or ("4500171") or ("4135789") or ("4494825") or ("4325610") or ("4536060")).PN.	USPAT
9	BRS	3650	adj o : adj	USPAT
7	BRS	3650	(cog or chip adj on adj glass same (control adj circuit\$ or semiconductor adj chip\$)) and ad<=19951219	USPAT
œ	BRS	3650	cog or chip adj on adj glass near10(control adj circuit\$ or semiconductor adj chip\$)	USPAT
<u>ი</u>	BRS	116	(cog or chip adj on adj glass same (control adj circuit\$ or semiconductor adj chip\$)) and @ad<=19951219 and liquid adj crystal	USPAT
10	BRS	13	single?crystal adj silicon adj chip\$	USPAT

	Type	Hits	Search Text	DBs
11	BRS		single?crystal adj silicon adj chip\$ with (control adj circuit\$)	USPAT
12	BRS	4	'   "5148301"   "5504348"   "5610742").	USPAT
13	BRS	4	("3807127"   "3954325"   "3961843"   "4283118"   "3807127"   "3954325"   "3961843"   "4283118").PN.	USPAT
14	BRS	367	semiconductor adj chip\$ with (control adj circuit\$)	USPAT
15	BRS	3916	(control adj circuit or semiconductor adj chip\$) same seal\$5	USPAT
16	BRS	23	(semiconductor adj chip\$ with (control adj circuit\$)) and ((control adj circuit or semiconductor adj chip\$) same seal\$5)	USPAT
17	BRS	195	: ()	US-PGPU B; EPO; JPO; DERWENT ; IBM TDB

	Type	#	Hits	Search Text	DBs
Н	BRS	L1	195	semiconductor adj chip\$ with (control adj circuit\$)	US-PGP UB; EPO; JPO; DERWEN T; IBM
8	BRS	1.2	7	1 same seal\$5	US-PGP UB; EPO; JPO; DERWEN T; IBM
К	BRS	F 3	306	semiconductor adj chip\$ same (control adj circuit\$)	US-PGP UB; EPO; JPO; DERWEN T; IBM
4	BRS	L4	ω	3 same seal\$5	US-PGP UB; EPO; JPO; DERWEN T; IBM

	Туре	#	Hits	Search Text	DBs
വ	BRS	1.5	179		US-PGP UB; EPO; JPO; DERWEN T; IBM
9	BRS	Tre	7		US-PGP UB; EPO; JPO; DERWEN T; IBM
7	BRS	L7	ĸ	5 and liquid adj crystal	US-PGP UB; EPO; JPO; DERWEN T; IBM

	Ð	1	Document ID	Issue Date	Pages	Title	Current OR
1		×	US 4494825 A	19850122	9	Fill port seal with first and second photosensitizers	349/154
2		⊠	US 4695490 A	19870922	9	Seal for liquid crystal display	428/1.53
ო			US 6091392 A	20000718	ω	Passive matrix LCD with drive circuits at both ends of the scan electrode applying equal amplitude voltage waveforms simultaneously to	345/100
4			US 4394067 A	19830719	5	Display device	349/153
5		Ø	US 3954325 A	19760504	Ŋ	Multilayer ceramic-based liquid crystal display	349/158
9			US 5849601 A	19981215	20	Electro-optical device and method for manufacturing the same	438/24
7		Ø	JP 04192446 A	19920710	و	RESIN-SEALED SEMICONDUCTOR DEVICE	***************************************
8		 ⊠	JP 05113555 A	19930507	ഹ	LIQUID CRYSTAL DISPLAY UNIT	
	-	-		-	į.		